

NTE107 Silicon NPN Transistor UHF Oscillator for Tuner

Description:

The NTE107 is a silicon NPN planar epitaxial transistor in a TO92 type package designed specifically for high frequency applications. This device is suitable for use as an oscillator in UHF television tuners.

Absolute Maximum Ratings: (T _A = +25°C unless otherwise specified)
Collector–Base Voltage, V _{CBO}
Collector–Emitter Voltage, V _{CEO}
Emitter–Base Voltage, V _{EBO}
Collector Current, I _C
Total Power Dissipation ($T_A = +25^{\circ}C$), P_T
Derate above +25°C
Operating Junction Temperature, T _J +100°C
Storage Temperature Range, T _{stq} –55° to +125°C
Lead temperature (During Soldering, 1/16" ±1/32" from case, 10sec), T _L +260°C

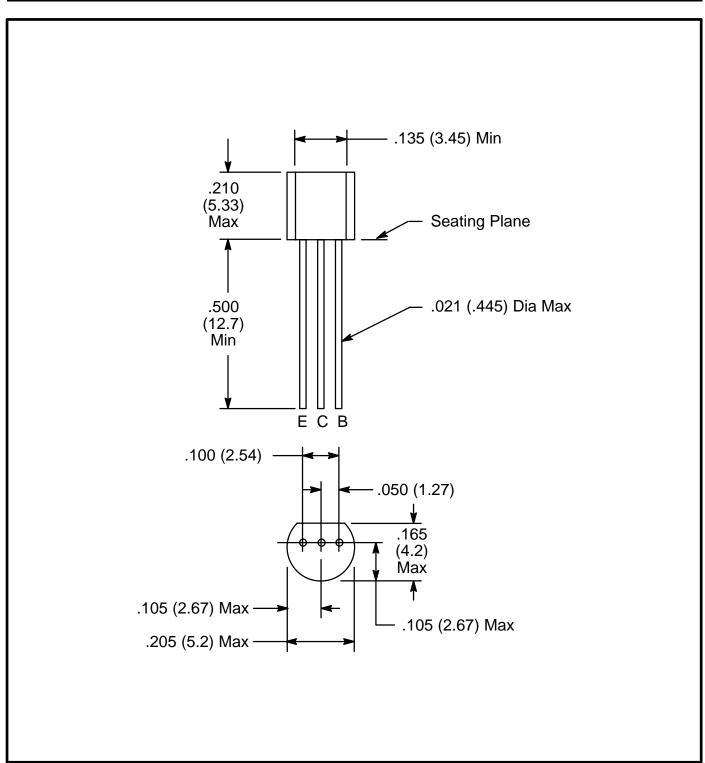
<u>Electrical Characteristics:</u> $(T_A = +25^{\circ}C \text{ unless otherwise specified})$

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit				
Static Characteristics										
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C = 100μA	30	_	_	V				
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _{CEO} = 3mA, Note 1	12	_	_	V				
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E = 100μA	3	_	_	V				
Collector Cutoff Current	I _{CBO}	$V_{CB} = 15V, I_{E} = 0$	_	_	0.5	μΑ				
Emitter Cutoff Current	I _{EBO}	$V_{EB} = 2V, I_C = 0$	_	_	0.5	μΑ				
Forward Current Transfer Ratio	h _{FE}	$V_{CE} = 10V$, $I_C = 8mA$	20	75	_					
Collector Saturation Voltage	V _{CE(sat)}	$I_C = 10$ mA, $I_B = 1$ mA	_	_	0.6	V				

Note 1. Pulse test: Pulse Width = $1\mu s$, Duty Cycle = 1%.

<u>Electrical Characteristics (Cont'd)</u>: $(T_A = +25^{\circ}C)$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit			
Dynamic Characteristics									
Current Gain-Bandwidth Product	f _T	$I_C = 5mA, V_{CE} = 10V, f = 100MHz$	700	_	2100	MHz			
Output Capacitance	C _{ob}	$V_{CE} = 10V, I_{E} = 0, f = 1MHz$	0.8	_	1.5	pF			
Noise Figure	NF	I_C = 1mA, V_{CB} = 6V, f = 60MHz, R_G = 400 Ω	-	4.0	6.5	dB			



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